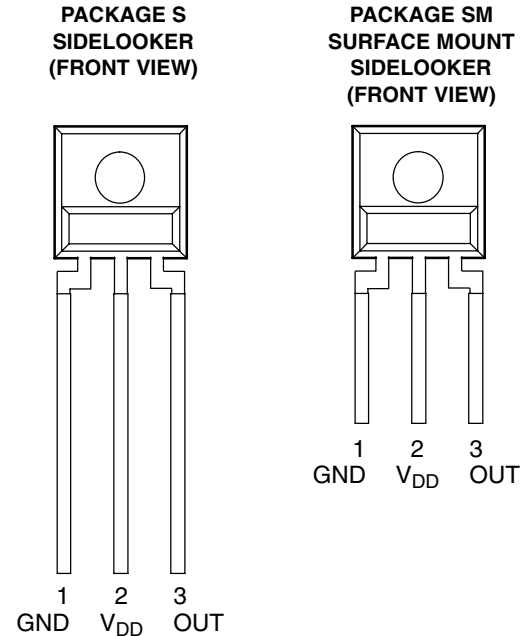


- High-Resolution Conversion of Light Intensity to Frequency With No External Components
- High Irradiance Responsivity . . . $2.3 \text{ kHz}/(\mu\text{W}/\text{cm}^2)$ at $\lambda_p = 524 \text{ nm}$
- Low Dark Frequency . . . $< 2 \text{ Hz}$ at 50° C
- Single-Supply Operation . . . 2.7 V to 5.5 V
- Stable $200 \text{ ppm}/^\circ\text{C}$ Temperature Coefficient
- Interfaces Directly to a Microcontroller
- RoHS Compliant (–LF Package Only)



Description

The TSL237 light-to-frequency converter combines a silicon photodiode and a current-to-frequency converter on a single monolithic CMOS integrated circuit. Output is a square wave (50% duty cycle) with frequency directly proportional to light intensity (irradiance) on the photodiode. The digital output allows direct interface to a microcontroller or other logic circuitry. The device has been temperature compensated for the ultraviolet-to-visible light range of 320 nm to 700 nm and responds over the light range of 320 nm to 1050 nm. The TSL237 is characterized for operation over the temperature range of -40°C to 85°C and is supplied in a 3-lead clear plastic side-looker package with an integral lens. When supplied in the lead (Pb) free package, the device is RoHS compliant.

For automotive and other extended temperature applications, please contact TAOS for information.

Functional Block Diagram



Available Options

DEVICE	T _A	PACKAGE – LEADS	PACKAGE DESIGNATOR	ORDERING NUMBER
TSL237	-40°C to 70°C	3-lead Sidelooker	S	TSL237S
TSL237	-40°C to 70°C	3-lead Sidelooker — Lead (Pb) Free	S	TSL237S–LF
TSL237	-40°C to 70°C	3-lead Surface-Mount Sidelooker — Lead (Pb) Free	SM	TSL237SM–LF

TSL237

HIGH-SENSITIVITY LIGHT-TO-FREQUENCY CONVERTER

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Terminal Functions

TERMINAL NAME	NO.	TYPE	DESCRIPTION
GND	1		Power supply ground (substrate). All voltages are referenced to GND.
OUT	3	O	Output frequency.
V _{DD}	2		Supply voltage.

Absolute Maximum Ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V _{DD} (see Note 1)	6 V
Operating free-air temperature range, T _A (see Note 2)	–40°C to 85°C
Storage temperature range, T _{stg} (see Note 2)	–40°C to 85°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds (S Package)	260°C
Reflow solder, in accordance with J-STD-020C or J-STD-020D (SM Package)	260°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to GND.

2. Long-term storage or operation above 70°C could cause package yellowing that will lower the sensitivity to wavelengths < 500nm.

Recommended Operating Conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V _{DD}	2.7	5	5.5	V
Operating free-air temperature range, T _A	–40		70	°C

Electrical Characteristics at V_{DD} = 5 V, T_A = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{OH} High-level output voltage	I _{OH} = –1 mA	4	4.5		V
V _{OL} Low-level output voltage	I _{OL} = 1 mA		0.25	0.4	V
I _{DD} Supply current			2	3	mA
Full-scale frequency [‡]		500		1000	kHz
Temperature coefficient of responsivity	Wavelength < 600nm, f _O = 50 kHz		±200		ppm/°C
k _{SVS} Supply-voltage sensitivity	V _{DD} = 5 V ±10%		±0.5		%/V

[‡] Full-scale frequency is the maximum operating frequency of the device without saturation.

Operating Characteristics at V_{DD} = 5 V, T_A = 25°C, λ_p = 524 nm (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f _O Output frequency	E _e = 21.8 μW/cm ²	40	50	60	kHz
f _D Dark frequency	E _e = 0 μW/cm ²	0	0.1		Hz
	E _e = 0 μW/cm ² , T _A = 50°C	0		2	Hz
R _e Irradiance responsivity			2.3		kHz/(μW/cm ²)
Nonlinearity [§]	f _O = 0 kHz to 10 kHz		±1%		%F.S.
Step response to full-scale step input		1 pulse of new frequency plus 1 μs			

[§] Nonlinearity is defined as the deviation of f_O from a straight line between zero and full scale, expressed as a percent of full scale.



TYPICAL CHARACTERISTICS

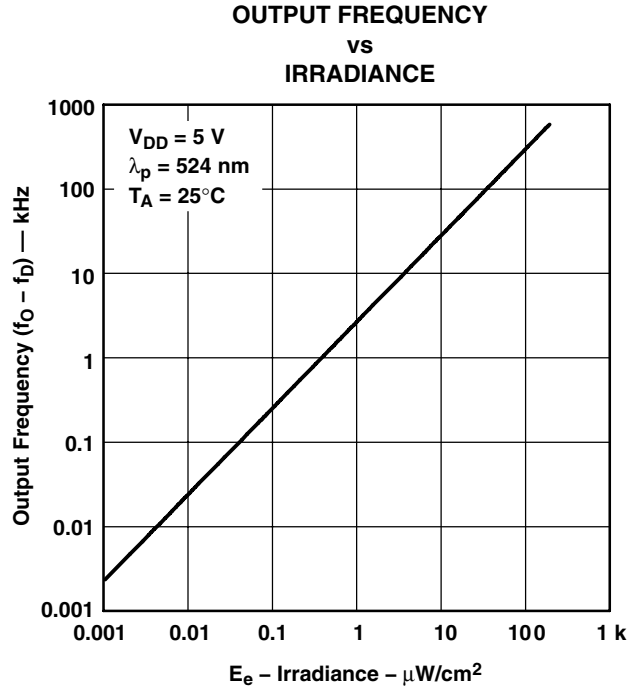


Figure 1

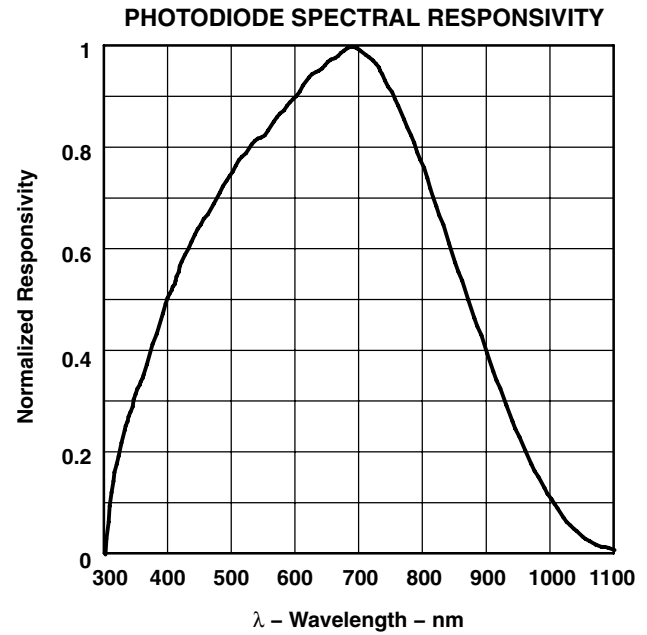


Figure 2

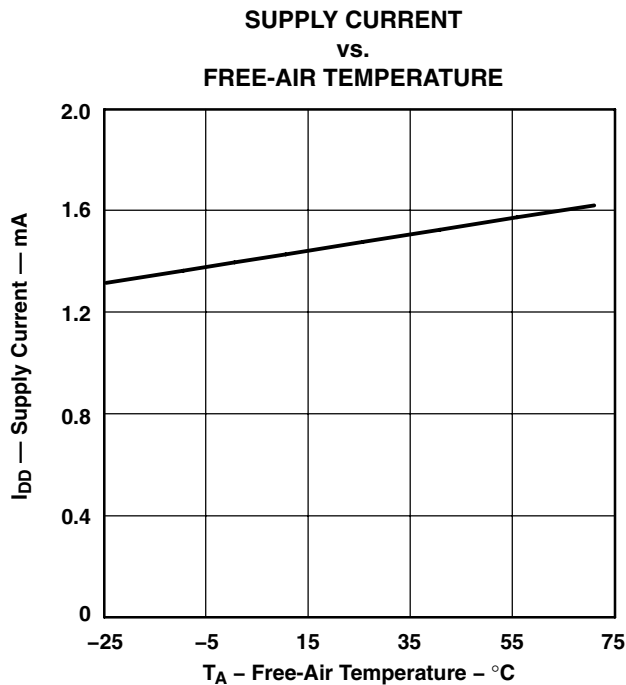


Figure 3

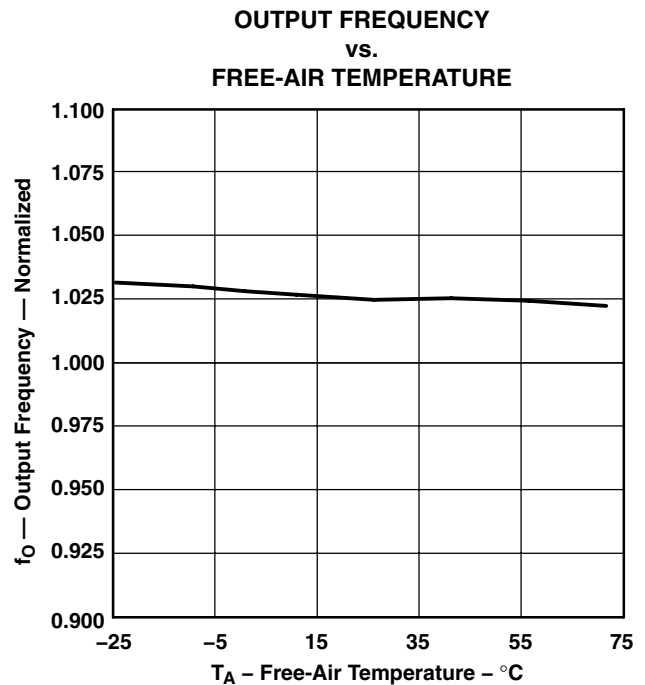


Figure 4

TYPICAL CHARACTERISTICS

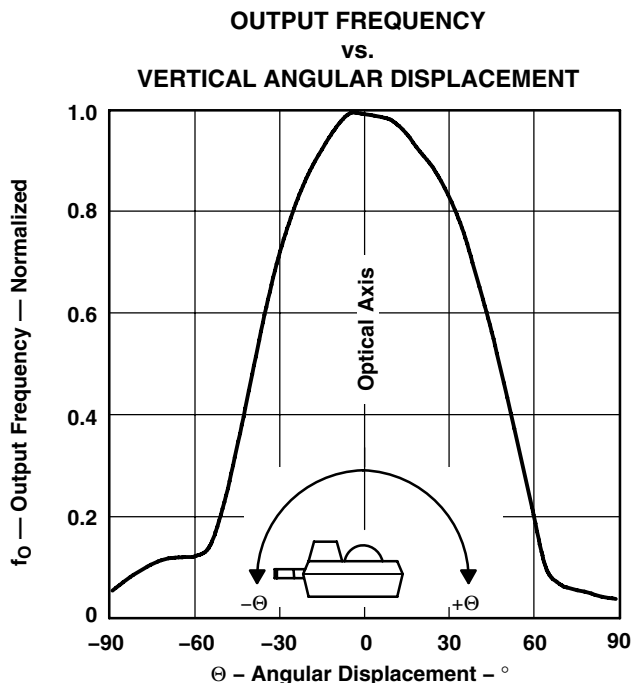


Figure 5

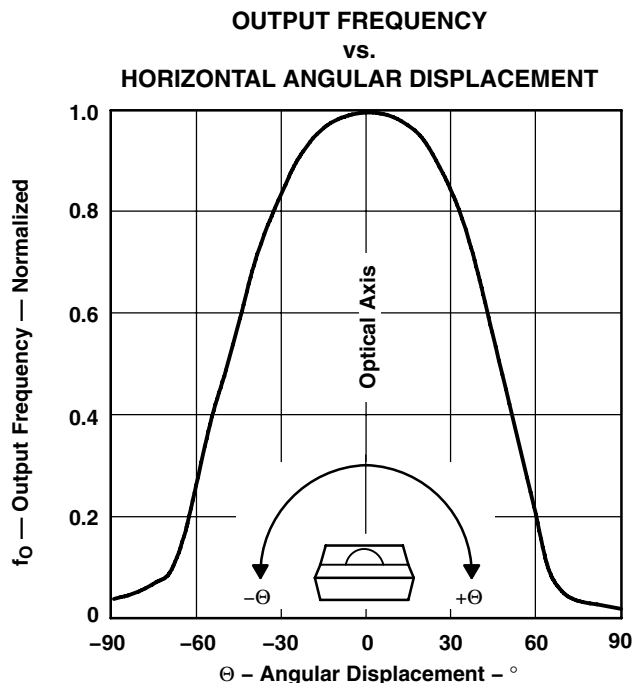


Figure 6

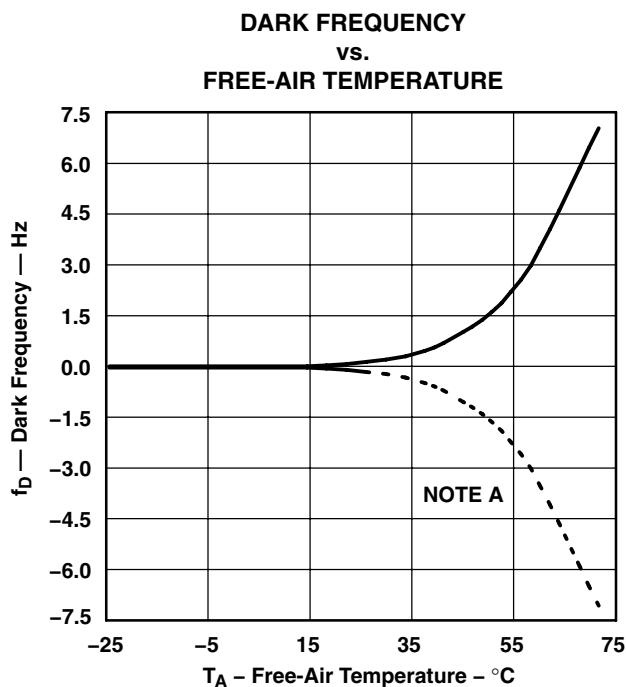


Figure 7

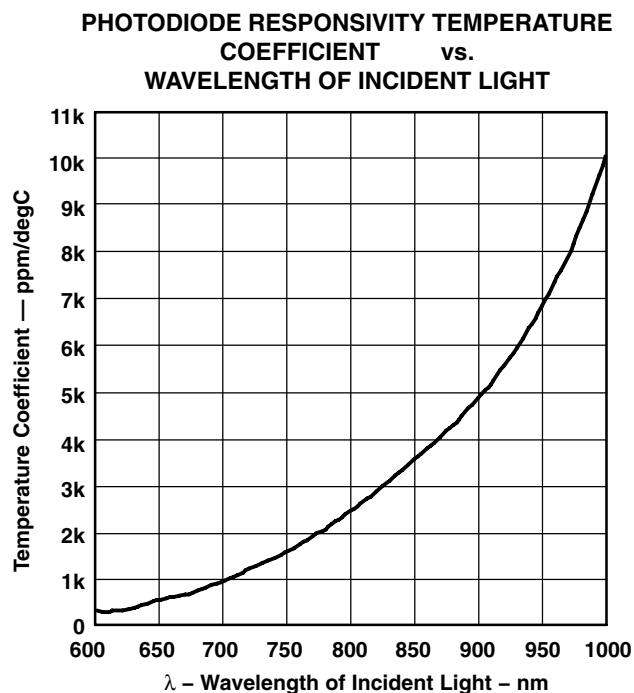


Figure 8

NOTE A: Internal offsets that result in dark frequency can be both positive and negative. The dashed line represents the case of negative offset in which an equivalent amount of light signal is required to obtain a non-zero output frequency.



APPLICATION INFORMATION

Power-Supply Considerations

Power-supply lines must be decoupled by a 0.01-μF to 0.1-μF capacitor with short leads placed close to the TSL237 (Figure 9). A low-noise power supply is required to minimize jitter on output pulse.

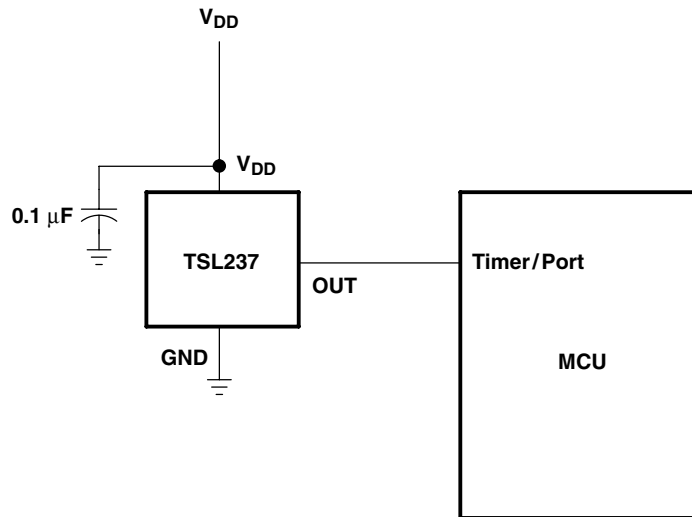


Figure 9. Typical TSL237 Interface to a Microcontroller

Device Operational Details

The frequency at the output pin (OUT) is given by:

$$f_O = f_D + (R_e)(E_e)$$

where:

- f_O is the output frequency
- f_D is the output frequency for dark condition ($E_e = 0$)
- R_e is the device responsivity for a given wavelength of light given in kHz/(μW/cm²)
- E_e is the incident irradiance in μW/cm²

f_D is a constant error term in the output frequency calculation resulting from leakage currents, and is independent of light intensity. The TSL237 die is trimmed to minimize the magnitude of this dark frequency component so that it can be neglected in the transfer function calculation. In many applications, measurement of the actual dark frequency may be impractical due to measurement times ranging from several seconds to several minutes, and the fact that some devices may never transition (zero dark frequency).

Output Interface

The output of the device is designed to drive a CMOS logic input over short distances. If lines greater than 12 inches in length are used on the output, a buffer or line driver is recommended.

APPLICATION INFORMATION

Measuring the Frequency

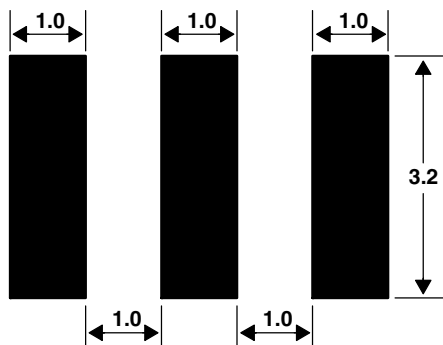
The choice of interface and measurement technique depends on the desired resolution and data-acquisition rate. For maximum data-acquisition rate, period-measurement techniques are used.

Period measurement requires the use of a fast reference clock with available resolution directly related to the reference-clock rate. The technique is employed to measure rapidly varying light levels or to make a fast measurement of a constant light source.

Maximum resolution and accuracy may be obtained using frequency-measurement, pulse-accumulation, or integration techniques. Frequency measurements provide the added benefit of averaging out random- or high-frequency variations (jitter) resulting from noise in the light signal. Resolution is limited mainly by available counter registers and allowable measurement time. Frequency measurement is well suited for slowly varying or constant light levels and for reading average light levels over short periods of time. Integration, the accumulation of pulses over a very long period of time, can be used to measure exposure — the amount of light present in an area over a given time period.

PCB Pad Layout

Suggested PCB pad layout guidelines for the SM surface mount package are shown in Figure 10.



- NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.

Figure 10. Suggested SM Package PCB Layout

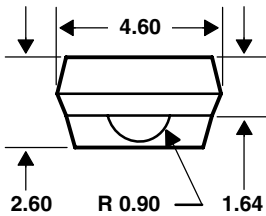
MECHANICAL DATA

The device is supplied in a clear plastic three-lead through-hole package.

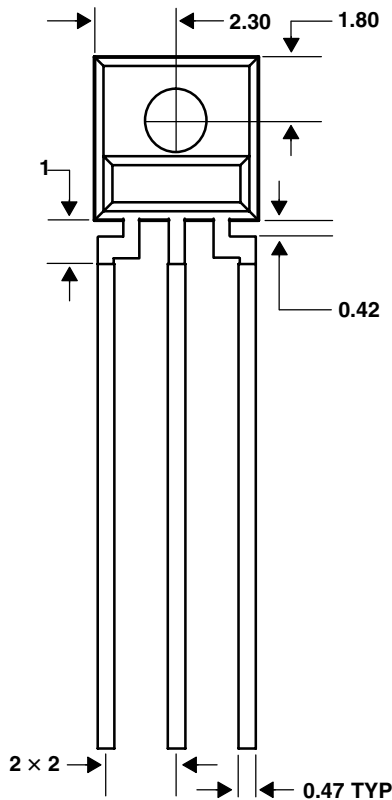
PACKAGE S

PLASTIC SINGLE-IN-LINE SIDE-LOOKER PACKAGE

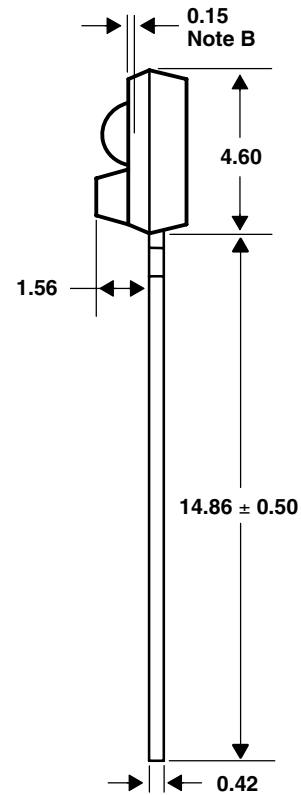
TOP VIEW



FRONT VIEW



SIDE VIEW



Lead Free
Available

- NOTES: A. All linear dimensions are in millimeters; tolerance is ± 0.25 mm unless otherwise stated.
 B. Dimension is to center of lens arc, which is located below the package face.
 C. The integrated photodiode active area is typically 0.92 mm^2 in size and is located in the center of the lens and 0.97 mm below the top of the lens surface.
 D. Index of refraction of clear plastic is 1.55.
 E. Lead finish for TSL237: solder dipped, 63% Sn/37% Pb. Lead finish for TSL237-LF: solder dipped, 100% Sn.
 F. This drawing is subject to change without notice.

Figure 11. Package S — Single-In-Line Side-Looker Package Configuration

TSL237
HIGH-SENSITIVITY
LIGHT-TO-FREQUENCY CONVERTER

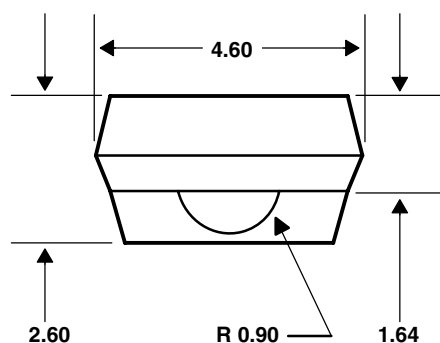
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MECHANICAL DATA

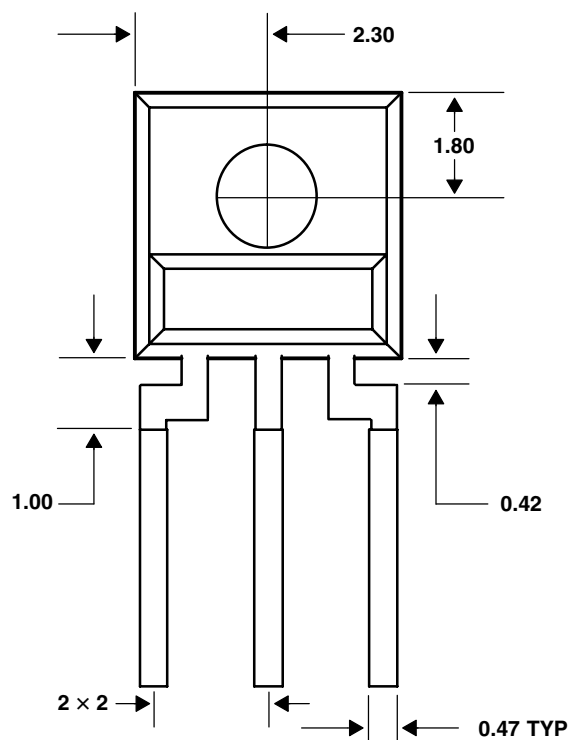
PACKAGE SM

PLASTIC SURFACE MOUNT SIDE-LOOKER PACKAGE

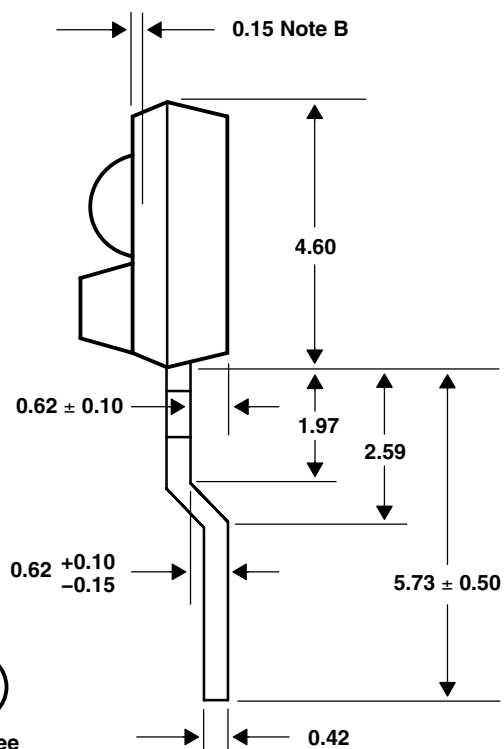
TOP VIEW



FRONT VIEW



SIDE VIEW



Lead Free

- NOTES: A. All linear dimensions are in millimeters; tolerance is ± 0.25 mm unless otherwise stated.
 B. Dimension is to center of lens arc, which is located below the package face.
 C. The integrated photodiode active area is typically located in the center of the lens and 0.97 mm below the top of the lens surface.
 D. Index of refraction of clear plastic is 1.55.
 E. Lead finish for TSL237SM-LF: solder dipped, 100% Sn.
 F. This drawing is subject to change without notice.

Figure 12. Package SM — Surface Mount Side-Looker Package Configuration



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